



(University of Choice)
**MASINDE MULIRO UNIVERSITY OF
SCIENCE AND TECHNOLOGY
(MMUST)**

**MAIN CAMPUS
UNIVERSITY EXAMINATIONS
2021/2022 ACADEMIC YEAR**

SECOND YEAR SECOND SEMESTER

MAIN EXAMINATIONS

**FOR THE DEGREE
OF
BACHELOR OF SCIENCE IN ELECTRICAL COMMUNICATION ENGINEERING**

COURSE CODE: ECE 224

COURSE TITLE: ELECTRICAL MEASUREMENTS

DATE: THURSDAY, APRIL, 28TH, 2022.

TIME: 8:00 – 10:00 AM

INSTRUCTIONS TO CANDIDATES

Question ONE (1) is compulsory
Answer Any Other TWO (2) questions

TIME: 2 Hours

MMUST observes ZERO tolerance to examination cheating

This Paper Consists of 5 Printed Pages. Please Turn Over.

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Question One (30mks)

- (a) i) With the aid of a block diagram, describe the elements of a measurement system. (8mks)
(6mks)
- ii) Explain the following static characteristics of instruments (2mks)
- Precision
 - Repeatability
 - Zero drift
 - Resolution
- (b) An iron–constantan thermocouple is to be used to measure temperatures between 0 and 400°C. If the e.m.f. at 150°C = 7.268 mV; e.m.f. at 400°C = 21.846 mV, determine the non-linearity error as a percentage of the full-scale reading at 150°C if a linear relationship is assumed between e.m.f. and temperature over the full range. (4mks)
- (c) i) Explain how strain gauge load cells can measure the weight of heavy duty trucks on a weighbridge. (10mks)
- ii) A strain gauge with a gauge factor of 4 and resistance of 350Ω is bonded on an Aluminium loadcell whose diameter is 5.6cm, length 30cm and Young's modulus $E = 70GN/m^2$. The strain gauge is connected into a bridge circuit with three other precision resistances each at 350Ω and supplied by +15V. If a weight of 4500N is exerted on the loadcell. Calculate;
- the strain in the beam
 - the percentage change in resistance
 - the offset voltage of the bridge
- (d) Briefly describe how Lissajous patterns can be used to determine the phase difference between two signals. (8mks)

Question Two (20mks)

- (a) i) With the aid of sketches, explain the working principle of Hall effect sensors and state three industrial applications. (12mks)
- ii) Distinguish between *Hall effect* and *magneto-resistive effect*
- iii) A specimen of silicon doped semiconductor of area 15mm × 1mm and 1mm thickness, has a hall coefficient of $3.55 \times 10^{-4} m^3/Coulomb$. Calculate the hall voltage when a current of 15mA is flowing and the flux density is 0.48Wb/m².

- (b) The circuit diagram in Figure 2 shows Maxwell's inductance-capacitance bridge. Show that the unknown inductance and its internal resistance are given by: (4mks)

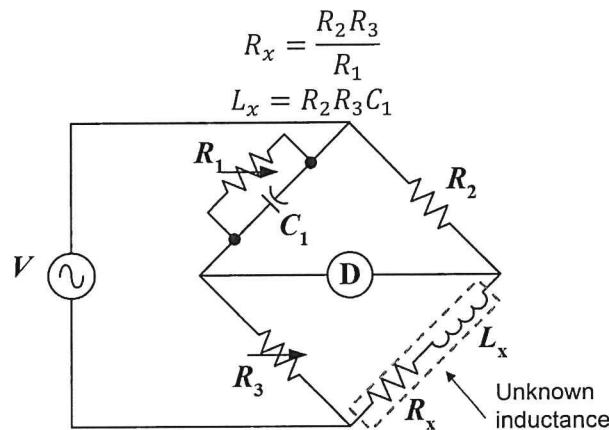
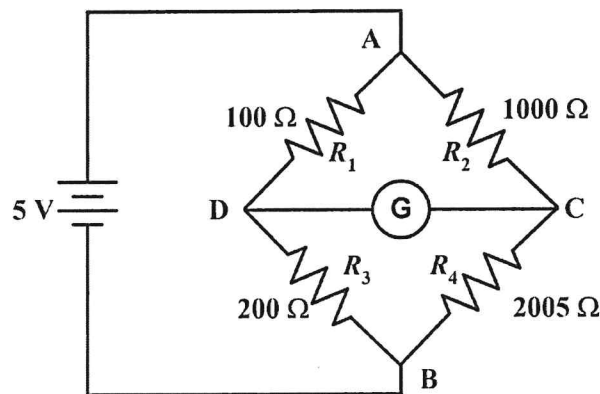


Figure 2

- (c) Briefly explain how a cathode ray oscilloscope can be used to measure voltage and current. (4mks)

Question Three (20mks)

- (a) The Figure 3 shows the schematic diagram of a Wheatstone bridge with values of the bridge elements. The battery voltage is 5V and its internal resistance negligible. The galvanometer has a current sensitivity of 10 mm/ μ A and an internal resistance of 100 Ω . Calculate the deflection of the galvanometer caused by the 5 Ω unbalance in arm BC. (8mks)



(a)

Figure 3

- (b) With aid of a block diagram, explain the working of a Cathode ray oscilloscope (8mks)
- (c) State and explain any four types of harmonic distortions (4mks)

Question 4 (20mks)

- (a) Discuss the benefits of using digital storage oscilloscope over the analogue storage oscilloscope. (6mks)
- (b) With the aid of a circuit diagram, explain how the Q-meter measures the quality factor of an unknown coil at radio frequencies. (6mks)
- (c) With the aid of a well labelled circuit diagram, describe how a Linear variable differential transformer can be used to measure small mechanical displacements. (8mks)

Question 5 (20mks)

- (a) With the aid of a well labelled block diagram, describe how current and voltage measurements can be obtained with a digital multimeter. (10mks)
- (b) A Piezoelectric crystal of charge sensitivity = $2pC/N$, area = $1cm^2$, $0.1 cm$ thickness and relative permittivity of 5 is subjected to a force of $0.01N$. Two metal electrodes measure the changes in the crystal. Young's modulus of the material $9 \times 10^{10}Pa$. Determine:
 - i) the voltage across the electrodes
 - ii) the change in crystal thicknessTake: $\epsilon_0 = 8.85 \times 10^{-12}F/m$ (6mks)
- (c) State and explain two types of digital displays. (4mks)